

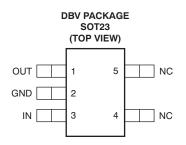
24-V Input Voltage, 150-mA, Ultralow I_Q Low-Dropout Regulators

FEATURES

- Wide Input Voltage Range: 2.5 V to 24 V
- Low 3.2-µA Quiescent Current
- Ground Pin Current: 3.4 µA at 100-mA IOUT
- Stable with Any Capacitor (> 0.47 μF)
- Available in SOT23-5 Package
- Operating Junction Temperature:
 -40°C to +125°C

APPLICATIONS

- Ultralow Power Microcontrollers
- E-Meters
- Fire Alarms/Smoke Detector Systems
- Handset Peripherals
- Industrial/Automotive Applications
- Remote Controllers
- Zigbee™ Networks
- PDAs
- Portable, Battery-Powered Equipment

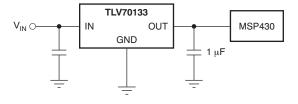


DESCRIPTION

The TLV701xx series of low-dropout (LDO) regulators are ultralow quiescent current devices designed for extremely power-sensitive applications. Quiescent current is virtually constant over the complete load current and ambient temperature range. These devices are an ideal power management attachment to low-power microcontrollers, such as the MSP430.

The TLV701xx operates over a wide operating input voltage of 2.5 V to 24 V. Thus, it is an excellent choice for both battery-powered systems as well as industrial applications that see large line transients.

The TLV701xx is available in a 3-mm × 3-mm SOT23-5 package that is ideal for cost-effective board manufacturing.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

AVAILABLE OPTIONS(1)

PRODUCT	V _{OUT}
TLV701 xxyyyz	XX is nominal output voltage (for example, 30 = 3.0 V) YYY is Package Designator Z is Package Quantity

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or visit the device product folder at www.ti.com.

ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range, unless otherwise noted.

		VALUE		UNIT
		MIN	MAX	
Voltage ⁽²⁾	IN	-0.3	24	V
Current source	OUT	Internally limited	i	
T	Operating junction, T _J	-40	+150	°C
Temperature	Storage, T _{stg}	-65	+150	O°
Flacture to the Dischause Betting (3)	Human body model (HBM) QSS 009-105 (JESD22-A114A)		2	kV
Electrostatic Discharge Rating ⁽³⁾	Charged device model (CDM) QSS 009-147 (JESD22-C101B.01)		500	V

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods my affect device reliability.

(2) All voltages are with respect to network ground terminal.

THERMAL INFORMATION

		TLV701XX	
	THERMAL METRIC ⁽¹⁾	DBV	UNITS
		5 PINS	
θ_{JA}	Junction-to-ambient thermal resistance	213.1	
θ_{JCtop}	Junction-to-case (top) thermal resistance	110.9	
θ_{JB}	Junction-to-board thermal resistance	97.4	°C // //
ΨЈТ	Junction-to-top characterization parameter	22.0	°C/W
ΨЈВ	Junction-to-board characterization parameter	78.4	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	n/a	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

³⁾ ESD testing is performed according to the respective JESD22 JEDEC standard.



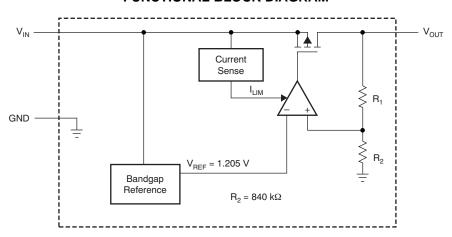
ELECTRICAL CHARACTERISTICS: $T_A = +25^{\circ}C$

All values are at T_A = +25°C, V_{IN} = $V_{OUT(nom)}$ + 1 V, I_{OUT} = 1 mA, and C_{OUT} = 1 μF , unless otherwise noted.

			TI	_V701xx		
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V	Input voltage range				24	V
Vo	Output voltage range		1.2		5	V
V _{OUT}	DC output accuracy		-2		2	%
ΔV_{O} for ΔV_{IN}	Line regulation	V _{OUT(NOM)} + 1 V < V _{IN} < 24 V		20	50	mV
	Load regulation	1 mA < I _{OUT} < 10 mA		6		mV
ΔV_O for ΔI_{OUT}		1 mA < I _{OUT} < 50 mA		19		mV
		1 mA < I _{OUT} < 100 mA		29	50	mV
M	Decreed walter as (1)	I _{OUT} = 10 mA		75		mV
V_{DO}	Dropout voltage ⁽¹⁾	I _{OUT} = 50 mA		400		mV
I _{CL}	Output current limit	V _{OUT} = 0 V	160		1000	mA
	Cround his aurrent	I _{OUT} = 0 mA		3.2	4.5	μΑ
I _{GND}	Ground pin current	I _{OUT} = 100 mA		3.4	5.5	μΑ
PSRR	Power-supply rejection ratio	f = 100 kHz, C _{OUT} = 10 μF		60		dB

(1) $V_{IN} = V_{OUT(NOM)} - 0.1 \text{ V}.$

FUNCTIONAL BLOCK DIAGRAM



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PIN CONFIGURATIONS

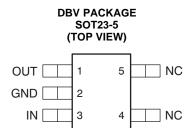


Table 1. Pin Descriptions

TLV701xx		
NAME	DBV	DESCRIPTION
GND	2	Ground
IN 3		Unregulated input voltage.
OUT	1	Regulated output voltage. Any capacitor 1 µF or greater between this pin and ground is needed for stability.
NC	4, 5	No connection. This pin can be left open or tied to ground for improved thermal performance.



TYPICAL CHARACTERISTICS

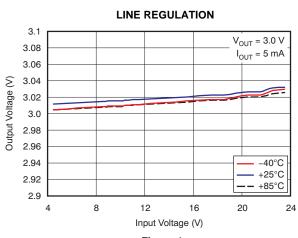


Figure 1.

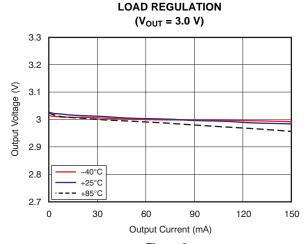


Figure 2.

OUTPUT VOLTAGE vs JUNCTION TEMPERATURE

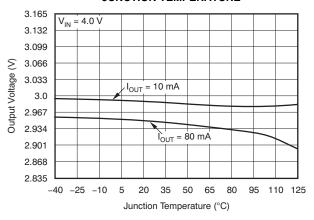


Figure 3.

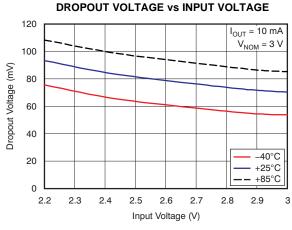


Figure 4.

DROPOUT VOLTAGE vs OUTPUT CURRENT

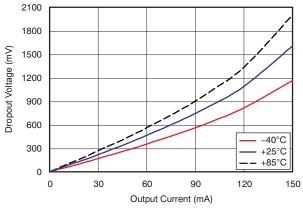


Figure 5.

GROUND CURRENT vs JUNCTION TEMPERATURE

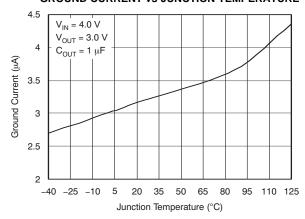


Figure 6.

PRODUCT PREVIEW



TYPICAL CHARACTERISTICS (continued)

GROUND PIN CURRENT vs OUTPUT CURRENT

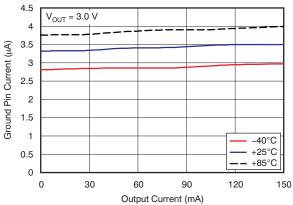


Figure 7.

CURRENT LIMIT vs JUNCTION TEMPERATURE

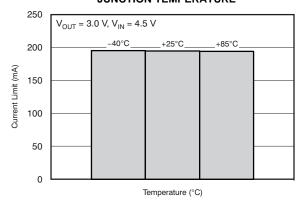


Figure 8.

OUTPUT SPECTRAL NOISE DENSITY vs FREQUENCY

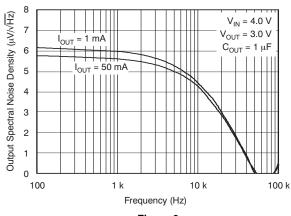


Figure 9.

PSRR vs FREQUENCY

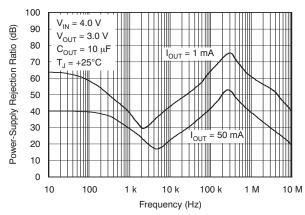


Figure 10.

LINE TRANSIENT RESPONSE

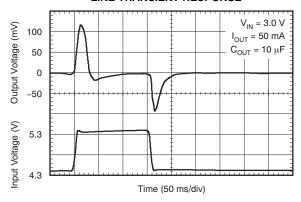


Figure 11.

LOAD TRANSIENT RESPONSE

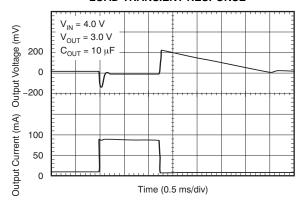


Figure 12.



APPLICATION INFORMATION

The TLV701xx series of devices belong to a family of ultralow, I_Q , low-dropout (LDO) regulators. I_Q remains fairly constant over the complete output load current and temperature range. The devices are ensured to operate over a temperature range of -40° C to $+125^{\circ}$ C.

INPUT AND OUTPUT CAPACITOR REQUIREMENTS

The TLV701 requires a 1-µF or larger capacitor connected between OUT and GND for stability. Ceramic or tantalum capacitors can be used. Larger value capacitors result in better transient and noise performance.

Although an input capacitor is not required for stability, when a 0.1-µF or larger capacitor is placed between IN and GND, it counteracts reactive input sources and improves transient and noise performance. Higher value capacitors are necessary if large, fast rise time load transients are anticipated.

BOARD LAYOUT RECOMMENDATIONS

Input and output capacitors should be placed as close to the device pins as possible. To avoid interference of noise and ripple on the board, it is recommended that the board be designed with separate ground planes for V_{IN} and V_{OUT} , with the ground plane connected only at the device GND pin. In addition, the ground connection for the output capacitor should be connected directly to the device GND pin.

POWER DISSIPATION AND JUNCTION TEMPERATURE

To ensure reliable operation, worst-case junction temperature should not exceed +125°C. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, $P_{D,max}$, which must be less than or equal to $P_{D,max}$.

The maximum power dissipation limit is determined using Equation 1:

$$P_{D(max)} = \frac{T_{J} max - T_{A}}{R_{\theta JA}}$$
(1)

where:

T_.Imax is the maximum allowable junction temperature.

 $R_{\mbox{\scriptsize \thetaJA}}$ is the thermal resistance junction-to-ambient for the package.

 T_A is the ambient temperature.

The regulator dissipation is calculated using Equation 2:

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT}$$
(2)

Power dissipation that results from quiescent current is negligible.

REGULATOR PROTECTION

The TLV701xx series of LDO regulators use a PMOS-pass transistor that has a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (for example, during power-down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting might be appropriate.

The TLV701xx features internal current limiting. During normal operation, the TLV701xx limits output current to approximately 250 mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. Take care not to exceed the rated maximum operating junction temperature of +125°C. Continuously running the device under conditions where the junction temperature exceeds +125°C degrades device reliability.

The ability to remove heat from the die is different for each package type, presenting different considerations in the printed circuit board (PCB) layout. The PCB area around the device that is free of other components moves the heat from the device to the ambient air. Using heavier copper increases the effectiveness in removing heat from the device. The addition of plated through-holes to heat-dissipating layers also improves heatsink effectiveness. Power dissipation depends on input voltage and load conditions. Power dissipation (P_D) is equal to the product of the output current and the voltage drop across the output pass element, as shown in Equation 2.





25-Oct-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Diawing		Qty	(2)	(6)	(3)		(4/5)	
TLV70130DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	YBVA	Samples
TLV70130DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	YBVA	Samples
TLV70133DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	YBWA	Samples
TLV70133DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	YBWA	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

25-Oct-2016

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV70130DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV70130DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV70133DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV70133DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV70130DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TLV70130DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TLV70133DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TLV70133DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

^{8.} Board assembly site may have different recommendations for stencil design.

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